#### **DISCRETE SEMICONDUCTORS**

## DATA SHEET



# **BYX132GL**High-voltage car ignition diode

Product specification Supersedes data of 2000 Jan 13

2001 Oct 02





#### High-voltage car ignition diode

#### BYX132GL

#### **FEATURES**

- · Glass passivated
- · High maximum operating temperature
- · Low leakage current
- · Excellent stability
- · Guaranteed avalanche energy absorption capability.

#### **APPLICATIONS**

- · Car ignition systems
- Automotive applications with extreme temperature requirements.

#### **DESCRIPTION**

Rugged glass package, using a high temperature alloyed construction.

The SOD119AB is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.

The package is designed to be used in an insulating medium such as resin, oil or SF6 gas.

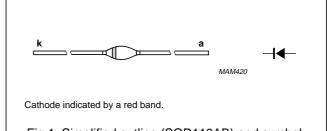


Fig.1 Simplified outline (SOD119AB) and symbol.

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>RRM</sub>	repetitive peak reverse voltage		_	2	kV
V <sub>RWM</sub>	crest working reverse voltage		_	2	kV
I <sub>F(AV)</sub>	average forward current		_	50	mA
I <sub>FRM</sub>	repetitive peak forward current		_	500	mA
I <sub>RSM</sub>	non-repetitive peak reverse current	t = 100 μs triangular pulse; T <sub>j max</sub> prior to surge	_	50	mA
T <sub>stg</sub>	storage temperature		-65	+200	°C
Tj	junction temperature	continuous	_	175	°C
		maximum 30 minutes	_	200	°C

#### **CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 10 mA	2.5	3.5	V
V <sub>(BR)R</sub>	reverse avalanche breakdown voltage	$I_R = 100 \mu A$	2.6	3.7	kV
I <sub>R</sub>	reverse current	$V_R = V_{RWMmax}$ ; $T_j = 175  ^{\circ}C$	_	30	μΑ

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	T <sub>amb</sub> = T <sub>leads</sub> ; lead length = 10 mm	90	K/W

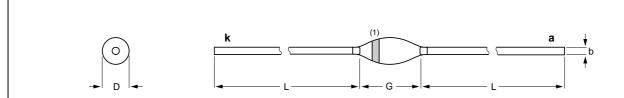
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#### **PACKAGE OUTLINE**

Hermetically sealed glass package; axial leaded; 2 leads

SOD119AB



#### **DIMENSIONS** (mm are the original dimensions)

UNIT	b	D max.	G max.	L min.	
mm	0.8	2.5	5.5	31.8	

0 2.5 5 mm

#### Note

1. The marking band indicates the cathode.

OUTLINE	OUTLINE REFERENCES		EUROPEAN	ICCUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOD119AB					98-12-04

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#### **DATA SHEET STATUS**

DATA SHEET STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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